

REV LTR	DESCRIPTION	DATE	APPVD.
-	Orig.	9/10/12	

**XSIS XE66S – L00, SERIES**  
**HC/ACMOS OSCILLATORS**  
**FOR SPACE APPLICATIONS**  
  
**450 KHz to 100 MHz**  
**( TO-5 Package, 3.3V )**

( Refer to Page 5 for Models with Reduced Screening & QCI )

REV STATUS OF SHEETS	REV																
	SHEET NO.	1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16
<b>APPROVALS</b>	<b>DATE</b>	<b>XSIS ELECTRONICS, INC.</b>															
PREP. S. Gupta	9/10/12	12620 W. 63 <sup>rd</sup> Street, Shawnee, KS 66216 USA															
ENG. M. Gupta	9/10/12	<b>XE66S – L00 SERIES HC/ACMOS</b>															
Q. A. M. Gupta	9/10/12	<b>"S" LEVEL OSCILLATORS</b>															
CUST. ENG.		FSC NO. 57051						DWG. NO. XE66S-L00									
CUST Q A.		SCALE N/A						SHEET 1 OF 9									

1. SCOPE: XE66S-L00, HC/ACMOS series, high reliability hybrid microcircuit crystal oscillators are specifically designed, produced and tested by Xsis Electronics, Inc. for use in space applications. These devices are of hybrid microcircuit technology conforming to MIL-PRF-55310, Type 1, Class 2 oscillators

2. APPLICABLE DOCUMENTS:

MIL-PRF-55310E	Oscillator, Crystal Controlled, General Specifications for
MIL-PRF-38534H	Hybrid Microcircuits, General Specifications for
MIL-STD-883H	Test Methods and Procedures for Microelectronics

3. REQUIREMENTS:

3.1 General: The individual item requirements shall be as specified herein.

3.2 Package: Kovar, 100 to 250 microinches nickel plated. Physical configuration shall be as shown in Figure 1. Thermal Resistance,  $\theta_{JC}$ : 50 °C / Watt

3.2.1 Lead finish: 50 to 70 micro-inches gold over 100 to 250 micro-inches nickel. Hot solder tinning with Sn60/Pb40 solder per MIL-PRF-55310 is optional at an additional cost.

3.2.2 Weight: 1.0 Gms typical, 1.2 Gms Max.

3.2.3 Lead Soldering: 260 °C for 10 seconds shall not degrade the performance.

3.3 Hermeticity: Resistance welded, hermetically sealed, leak rate of  $1(10)^{-8}$  atm-cc/s Max.

3.4 Marking: As a minimum, the parts shall be marked with Xsis P/N, Xsis cage code, ESD symbol, date code and serial number.

3.5 Absolute Maximum Ratings: Unless otherwise specified, absolute maximum ratings shall be as follows:

Supply Voltage	-0.5 to +5 VDC
Operating Free-Air Temperature Range	-55 °C to +125 °C
Storage Temperature	-55 °C to +125 °C

3.6 Electrical Characteristics: See Table I

3.6.1 Total Dose Radiation: Hybrid Microcircuit Crystal Oscillators shall be capable of meeting the electrical characteristics of Para. 3.6 after being exposed to total ionizing dose radiation of 100 krad as per MIL-STD-883, method 1019.

3.7 Hybrid Elements:

3.7.1 Quartz Crystals: High grade cultured quartz crystals shall be used. As an option, Xsis will use premium Q swept quartz crystals at an additional charge. Crystal element evaluation shall be in accordance with MIL-PRF-55310. If swept quartz crystal is required, it must be specified on the purchase order.

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- 3.7.2 Passive Elements: Established Reliability (ER) QPL components, failure level R minimum shall be used or element lot evaluation shall be as per MIL-PRF-55310, class S, or MIL-PRF-38534, Appendix C, Class K as applicable.
- 3.7.3 Microcircuit die shall be from lots that have passed the element evaluation per MIL-PRF-55310, Appendix B, Level S, except testing per Subgroup 5 is omitted. Subgroup 5 testing is circuit configuration dependent, therefore, it is more effectively performed at the oscillator level as explained in Paragraph 3.7.4 herein.
- 3.7.4 Microcircuit die used in the oscillator shall be from NSC/FC 54ACT family and must be from wafer lot that has been successfully tested in the oscillator for ionizing radiation of up to 100 krad. Xsis Electronics has also performed SET & SEL testing on the microcircuit die. Test reports are available on request.
- 3.7.5 Workmanship, Rework and Process controls shall be in accordance with the requirements of MIL-PRF-55310.
- 3.7.6 Lot Traceability: Production lot for these oscillators shall be homogenous. Each element used in the production lot shall be traceable to a single lot. Swept quartz shall be traceable to the quartz bar, and its applicable processing details.
4. Quality Assurance Provisions: The quality assurance provisions shall be per MIL-PRF-55310, except as specified herein.
- 4.1 100% Screening: The 100% screening shall be performed as per Table II. PDA requirements for nondestructive bond pull and burn-in shall be as specified below.
- 4.2 PDA for Non-destruct Bond Pull: Unless otherwise specified, PDA shall be 2% of total number of wires or 1 wire whichever is greater.
- 4.3 PDA for Burn-in: Unless otherwise specified, PDA for burn-in shall be 2% or 1 oscillator whichever is greater and shall be applicable to +23 °C and/or +25 °C static tests only. In addition Delta Calculation shall be performed after Burn-in and shall count for PDA. All measured values for Delta Calculation shall be recorded. Parts that exceed the specified delta limits shall be rejected and be counted for PDA. Delta Calculation shall be performed at 3.3 VDC for the following parameters:
- |                   |                     |
|-------------------|---------------------|
| Input Current     | 10% change Maximum  |
| Output High Level | 10% change Maximum  |
| Output Low Level  | 0.1V change Maximum |
- 4.4 Group A inspection shall be in accordance with MIL-PRF-55310 for product level S.
- 4.5 Group B inspection ( 30 day aging ) shall be in accordance with MIL-PRF-55310 for product level S. In order to expedite delivery, by customer request, the aging test can be ended after 15 days if the amount of frequency aging is less than 50% of the 30 day specification limit.
- 4.6 Oscillators shall be capable of meeting group C inspection per MIL-PRF-55310. Generic group C inspection data on similar parts may be used to satisfy this requirement. When specified by the Customer, Xsis Electronics will perform Group C testing at an additional charge.

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4.7 Inspection and Test Data: Unless otherwise specified in the purchase order, the following Inspection and test data documentation shall be supplied with the parts.

Certificate of Conformance  
Summary of Class "S" screening Test Results  
PDA Calculations for Non-Destruct Bond Pull and Burn-in  
Summary of Elements Lot Traceability  
Electrical Tests before and after Burn-in  
Group A Inspection Summary  
Group B (30 day Aging) Data  
Radiographic Inspection Certificate

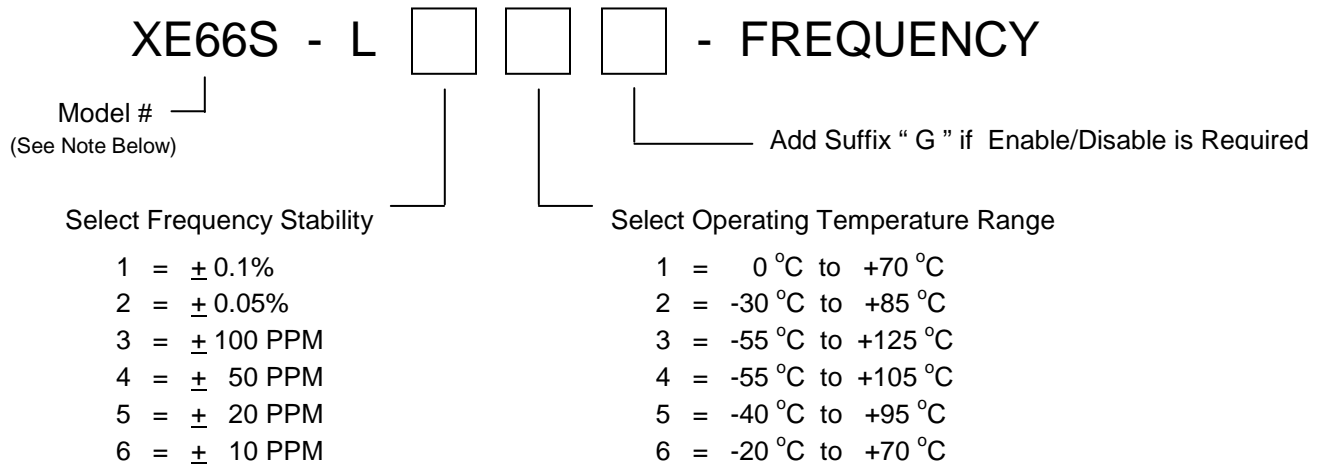
4.8 The following test and inspection options are available at customer request.

Customer Source Inspection for Pre-Cap and Final  
Group C Inspection per MIL-PRF-55310 on 4 or 8 units  
DPA (Destructive Physical Analysis)  
MIL-PRF-38534, Group B Inspection  
MIL-PRF-38534, Group C Inspection

5.0 Preservation, Packaging and Packing: The oscillators shall be clean, dry and packaged in a manner to provide adequate protection against electrostatic discharge, corrosion, deterioration and physical damage during shipment.

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6.0 Part Numbering Example:



(Frequency Stability Options 5 & 6 are not available for all Temperature Range Options)

P/N Example: XE66S - L43 - 24.000 MHz = 24.000 MHz, Class "S" Oscillator, ± 50 PPM Frequency Stability over an operating temperature range of -55 °C to +125 °C.

**NOTE:** Following additional models are available for applications that can accommodate reduced level of screening and quality conformance inspection:

**XE66H:** Model XE66H is same as Model XE66S except as follows:

- Group A inspection is per MIL-PRF-55310, Class B
- Group B inspection (30 day aging ) per MIL-PRF-55310 is not applicable

**XE66E:** Model XE66E uses the same design and elements as Model XE66S except as follows:

- 100% screening is as per Table III herein
- PDA for Burn-in is 10% or 1 unit whichever is greater
- Delta measurements of paragraph 4.3 are not applicable
- Group A inspection is as per MIL-PRF-55310, Class B
- Group B inspection (30 day aging ) per MIL-PRF-55310 is not applicable

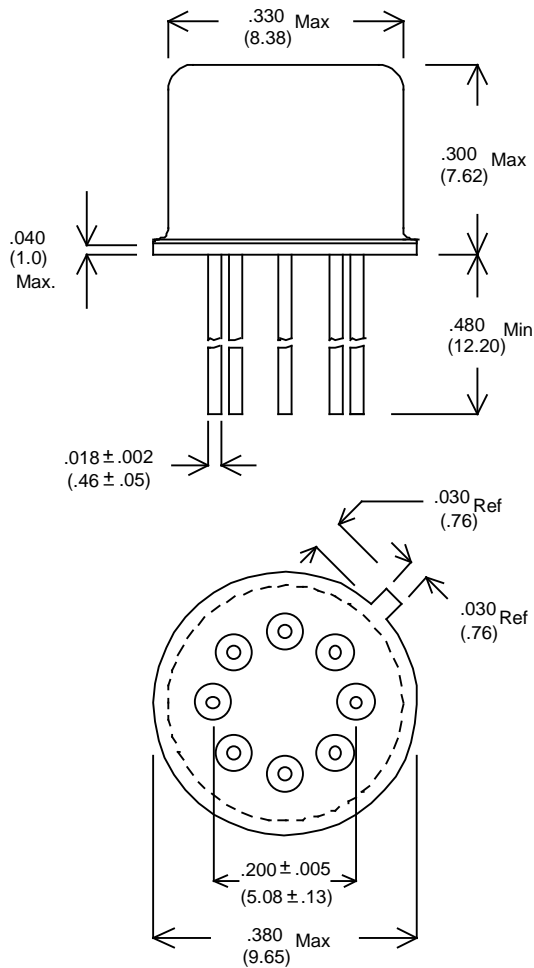
**XE66B:** Model XE66B is same as Model XE66E except as follows:

- Active and Passive Elements are as per MIL-PRF-55310, Class B. Microcircuit die is similar to the one used in Model XE66S but is not from radiation tested wafer lot.

**XE66P:** Model XE66P is a form, fit and function equivalent prototype of Model XE66S.

- Prototypes may use commercial grade elements and are not screened. Quality Conformance inspection is not applicable.

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Pin#	Function
3	E/D (Optional)
4	GND/CASE
5	OUTPUT
8	B+
All Others	N/C

**Enable/Disable Input:** A "Low" level at the input disables the Output into a high impedance state. Enable/Disable Input has internal pull-up.

Dimensions Inches ( mm )

Figure 1 - Package Configuration & Pin Connections

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**TABLE I – Electrical Characteristics**

Parameter	Spec. Limits
Frequency Range	450 KHz to 100 MHz
Frequency Accuracy at 23 °C	± 15 PPM Max.
Frequency Stability Vs Temperature	See Options in Paragraph 6.0
Operating Temperature Range	See Options in Paragraph 6.0
Input Voltage	+ 3.3 VDC ± 10%
Input Current at 3.3V ( no load )	
450.00 KHz to 5.00 MHz	3 mA Max.
5.01 MHz to 10.00 MHz	5 mA Max.
10.01 MHz to 20.00 MHz	8 mA Max.
20.01 MHz to 30.00 MHz	10 mA Max.
30.01 MHz to 40.00 MHz	15 mA Max.
40.01 MHz to 50.00 MHz	20 mA Max.
50.01 MHz to 100.00 MHz	35 mA Max.
Output Waveform	Square Wave, HC/ACMOS
Output Duty Cycle	55/45% Max
Output Load	10K    15 pF
High Output Level	0.9 VDD Min
Low Output Level	0.1 VDD Max.
Rise & Fall Times	
450.00 KHz to 25.00 MHz	5 nS Max
25.01 MHz to 45.00 MHz	4 nS Max.
45.01 MHz to 100.00 MHz	3 nS Max.
Start-up Time	10 mS Max.
Phase Jitter	0.3 pS rms typ, (10 KHz to 20 MHz Integrated )
Frequency Stability Vs Supply Voltage	± 4 PPM Max. for 10% change in Voltage
Frequency Aging @ 70 °C	1.5 PPM Max. /30 days, 3 PPM Max. /year

Contact Xsis Engineering for any other special Requirements.

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**Table II - Models XE66S & XE66H, Screening (100%)**

Test - Inspection	Test Method – Condition
Nondestructive Bond Pull	MIL-STD-883, Method 2023
Internal Visual	MIL-STD-883, Method 2017, Level S
Stabilization Bake ( Prior to Seal ) <sup>1/</sup>	MIL-STD-883, Method 1008, Condition C ( +150 °C ), 48 hours minimum
Thermal Shock	MIL-STD-883, Method 1011, Condition A
Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Constant Acceleration	MIL-STD-883, Method 2001, Condition A Y <sub>1</sub> axis only ( 5000 G )
Seal ( Fine and Gross Leak )	MIL-PRF-55310, Para. 4.8.2.2.2
Particle Impact Noise Detection ( PIND )	MIL-STD-883, Method 2020, Condition A
Radiographic Inspection	MIL-STD-883, Method 2012, Class S
Electrical Tests: Record all measurements.  Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal Supply Voltage, Specified load, +23 °C  MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23
Burn-in ( load )	+125 °C, Nominal Supply Voltage and Burn-in load, 320 Hours Minimum
Electrical Tests: Record all measurements.  Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal and Extreme Supply Voltages, Specified load, +23 °C and operating temperature extremes,  MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23

<sup>1/</sup> Vacuum bake and maintain oscillators in dry nitrogen per MIL-PRF-55310.

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Table III - Models XE66E & XE66B, Screening (100%)

Test - Inspection	Test Method – Condition
Nondestructive Bond Pull	MIL-STD-883, Method 2023
Internal Visual	MIL-STD-883, Method 2017, Level B
Stabilization Bake ( Prior to Seal ) <u>1/</u>	MIL-STD-883, Method 1008, Condition C ( +150 °C ), 24 hours minimum
Temperature Cycling	MIL-STD-883, Method 1010, Condition B
Constant Acceleration	MIL-STD-883, Method 2001, Condition A Y <sub>1</sub> axis only ( 5000 G )
Seal ( Fine and Gross Leak )	MIL-PRF-55310, Para. 4.8.2.2.2
Particle Impact Noise Detection ( PIND )	MIL-STD-883, Method 2020, Condition A
Electrical Tests:  Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal Supply Voltage, Specified load, +23 °C Verify all parameters  MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23
Burn-in ( load )	+125 °C, Nominal Supply Voltage and Burn-in load, 160 Hours Minimum
Electrical Tests:  Input Current Output Frequency Output Voltage Levels Output Rise & Fall Times Output Duty Cycle	Nominal Supply Voltage, Specified load, +23 °C and verify frequency at temperature extremes.  MIL-PRF-55310, Para. 4.8.5 MIL-PRF-55310, Para. 4.8.6 MIL-PRF-55310, Para. 4.8.21.3 MIL-PRF-55310, Para. 4.8.22 MIL-PRF-55310, Para. 4.8.23

1/ Vacuum bake and maintain oscillators in dry nitrogen per MIL-PRF-55310.

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